compound transistor μ **PA104**

HIGH FREQUENCY NPN TRANSISTOR ARRAY

FEATURES

NEC

- 9 GHz CONFIGURABLE TRANSISTOR BASED OR/NOR CIRCUITRY
- OUTSTANDING hFE LINEARITY
- TWO PACKAGE OPTIONS: μPA104B: Studded ceramic package provides superior thermal dissipation μPA104G: Reduced circuit size due to 14-pin plastic SOP package for surface mounting
- EXCELLENT FOR ANALOG ADDITIONS & FORMATION OF 2-INPUT OR/NOR GATES

DESCRIPTION AND APPLICATIONS

The μ PA104 is a user-configurable, Si bipolar transistor array for formation of high speed OR/NOR gates. Its internal transistor configuration and external connection options allow the user considerable flexibility in its application. Its high gain bandwidth product (fr = 9 GHz) make it applicable for electro-optical, signal processing, cellular telephone systems, instrumentation, and high speed gigabit logic circuits.

ORDERING INFORMATION

PART NUMBER PACKAGE		
μΡΑ104Β-Ε1	14-pin ceramic package	
μPA104G-E1	14-pin plastic SOP (225 mil)	

ABSOLUTE MAXIMUM RATINGS ($T_A = +25 \ ^{\circ}C$)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vсво*	Collector to Base Voltage	V	15
Vceo*	Collector to Emitter Voltage	V	6
Vево*	Emitter to Base Voltage	V	2.5
lc*	Collector Current	mA	40
Рт	Power Dissipation		
	μPA104B	mW	650
	μPA104G	mW	350
TJ	Junction Temperature		
	μPA104B	°C	200
	μPA104G	°C	125
Тѕтс	Storage Temperature		
	μPA104B	°C	-55 to +200
	μPA104G	°C	-55 to +125

* Absolute maximum ratings for each transistor.

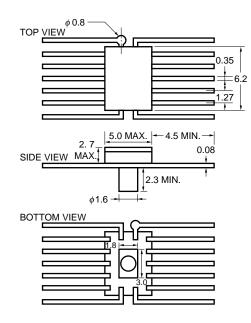
Caution electro-static sensitive devices

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PACKAGE DIMENSIONS (UNIT: mm)

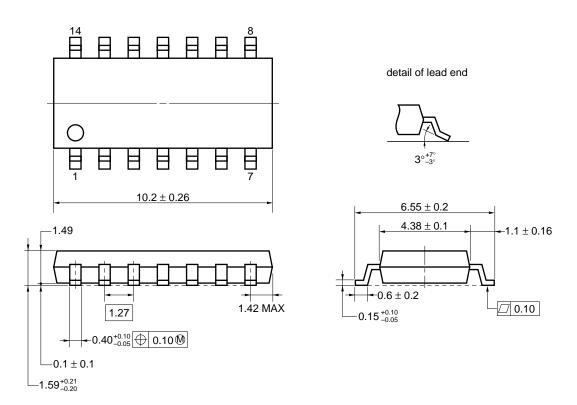
μ**ΡΑ104Β**

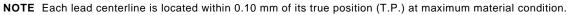
14 PIN CERAMIC PACKAGE





* 14 PIN PLASTIC SOP (225 mil)





See connection diagram for description of leads.

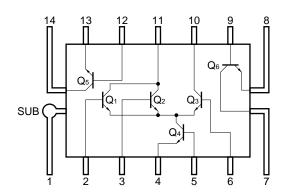
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN.	TYP.	MAX.
Ісво	Collector Cutoff Current at V_{CB} = 5 V, I_E = 0 (Q1 thru Q6)	μΑ			1.0
Іево	Emitter Cutoff Current at V_{EB} = 1 V, Ic = 0 (Q4 thru Q6)	μA			1.0
hfe	Direct Current Amplification at Vce = 3 V, Ic = 5 mA (Q4 and Q6)		40	100	250
Ссв	Collector to Base Capacitance at V_{CB} = 3 V, f = 1 MHz (Q3, Q5, Q6)	pF		0.9	1.8
Сев	Emitter to Base Capacitance at V_{EB} = 0, f = 1 MHz (Q4 thru Q6)	pF		1.4	2.8
Ccs	Collector/Substrate Capacitance, Vcs = 3 V, f = 1 MHz (Q3, Q5, Q6)	pF		1.4	2.8
fт	Gain Bandwidth Product* at V_{CE} = 3 V, Ic = 10 mA	GHz		9.0	

ELECTRICAL CHARACTERISTICS (Unless otherwise specified T_A = +25 °C µPA104B, µPA104G common)

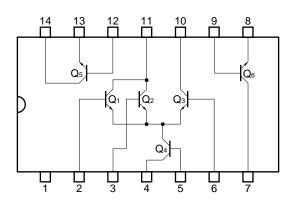
* Measured by installing a single transistor in a Micro-X package: the value shown is a reference value.

CONNECTION DIAGRAM (Top View)

μ**ΡΑ104Β**



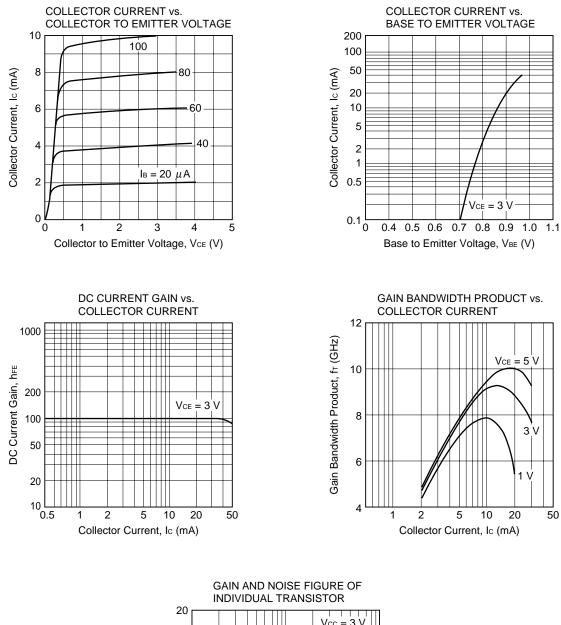
μ**ΡΑ104G**

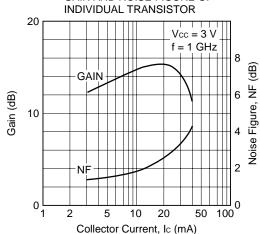


Note: Substrate should be connected to the lowest voltage point in order to prevent latch-up.

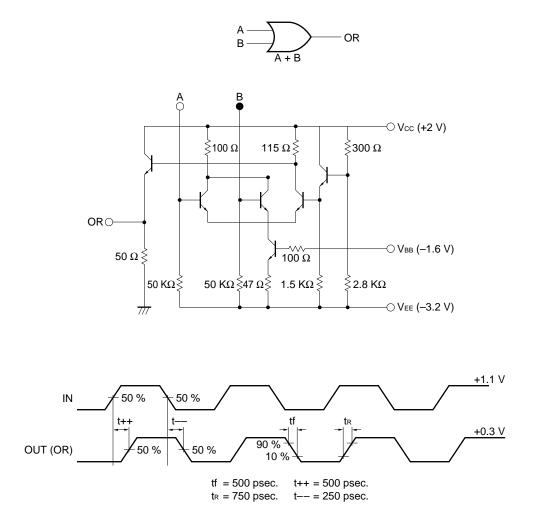
TYPICAL PERFORMANCE CHARACTERISTICS (T_A = +25 °C)

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TYPICAL APPLICATION



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as wide as possible to maintain the minimum ground impedance (to prevent undesired oscillation).
- (3) Design circuits connected Sub pin to the lowest voltage to prevent latch-up.
- (4) Design circuits as each pin voltage difference within 15 V maximum.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering methods and conditions than the recommended conditions are to be consulted with our sales representatives.

μ PA104G

Soldering process	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Package peak temperature: 235 °C, Hour: within 30 s. (more than 210 °C), Time: 2 times, Limited days: no. ^{Note}	IR35-00-2
VPS	Package peak temperature: 215 °C, Hour: within 40 s. (more than 200 °C), Time: 2 times, Limited days: no. ^{Note}	VP15-00-2
Wave soldering	Soldering tub temperature: less than 260 °C, Hour: within 10 s. Time: 1 time, Limited days: no. ^{Note}	WS60-00-1
Pin part heating	Pin area temperature: less than 300 °C, Hour: within 3 s./pin Limited days: no. ^{Note}	

μ**ΡΑ104Β**

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 10 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	
Partial heating method	Terminal temperature: 260 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

Note It is the storage days after opening a dry pack, the storage conditions are 25 °C, less than 65 % RH.

Caution The combined use of soldering method is to be avoided (However, except the pin area heating method).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]

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 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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